

2N3773

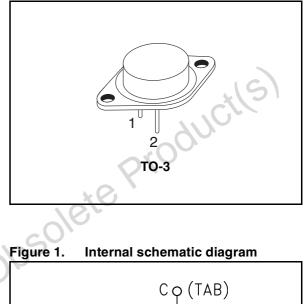
High power NPN transistor

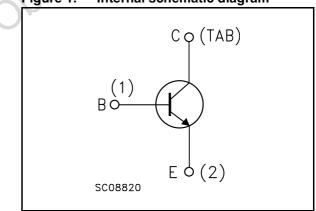
Features

- High power dissipation
- Low collector-emitter saturation voltage

Description

The device is a planar NPN transistor mounted in TO-3 metal case. It is intended for linear amplifiers and inductive switching applications.





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Order code	Marking	Package	Packaging	
2N3773	2N3773	TO-3	Tray	

1 Electrical ratings

Table 2.	Absolute	maximum	ratings
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Symbol	Parameter	Value	Unit
V _{CEO}	Collector-emitter voltage (I _B = 0)	140	V
V _{CEV}	Collector-emitter voltage (V _{BE} = -1.5 V)	160	V
V _{CBO}	Collector-base voltage (I _E = 0)	160	V
V _{EBO}	Emitter-base voltage (I _C = 0)	7	V
Ι _C	Collector current		SA
I _{CM}	Collector peak current (t _P < 5 ms)		А
Ι _Β	Base current		А
I _{BM}	Base peak current (t _P < 1 ms)	15	А
P _{tot}	Total dissipation at $T_c \le 25 \text{ °C}$	150	W
T _{stg}	Storage temperature	-65 to 200	°C
Тj	Max. operating junction temperature	200	°C

Table 3. Thermal data

	Symbol	S Parameter		Value	Unit	
	R _{thj-case}	Thermal resistance junction-case Max		1.17	°C/W	
obsole	te P	, 10010.				

Electrical characteristics 2

(T_{case} = 25 °C unless otherwise specified)

Symbol	Parameter	Test co	nditions	Min.	Тур.	Max.	Unit
I _{CEV}	Collector cut-off current (V _{BE} = -1.5 V)	V _{CE} = 140 V V _{CE} = 140 V	T _C = 150 °C			2 10	mA mA
I _{CEO}	Collector cut-off current $(I_B = 0)$	V _{CE} = 120 V				10	mA
I _{CBO}	Collector cut-off current $(I_E = 0)$	V _{CB} = 140 V			(2	mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 7 V		0	20	5	mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 0.2 A	leter	140			V
V _{CEV(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (V _{BE} = -1.5 V)	$I_{\rm C} = 0.1$ A).	160			v
V _{CER(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (R _{BE} = 100 Ω)	I _C = 0.2 A		150			v
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = 8 A I _C = 16 A	I _B = 0.8 A I _B = 3.2 A			1.4 4	V V
V _{BE} ⁽¹⁾	Base-emitter voltage	I _C = 8 A	$V_{CE} = 4 V$			2.2	V
h _{FE} ⁽¹⁾	DC current gain	I _C = 8 A I _C = 16 A	V _{CE} = 4 V V _{CE} = 4 V	15 5		60	
I _{s/b}	Second Breakdown Collector Current	V _{CE} = 30 V t = 1 s (non re	epetitive)	5			A

Table 4.	Electrical characteristics

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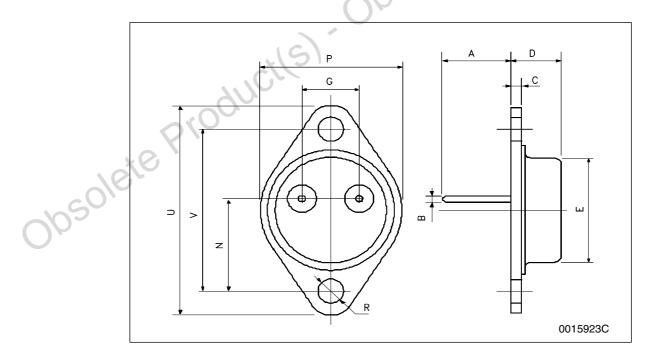
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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TO-3 mechanical data				
DIM.		mm.		
	min.	typ	max.	
A	11.00		13.10	
В	0.97		1.15	
С	1.50		1.65	
D	8.32		8.92	
E	19.00		20.00	
G	10.70		11.10	
N	16.50		17.20	
Р	25.00		26.00	
R	4.00		4.09	
U	38.50	161	39.30	
V	30.00	60.	30.30	





4 Revision history

Table 5.Document revision history

Date	Revision	Changes
03-Apr-2006	1	Initial release.
10-Oct-2008	2	Content reworked to improve readability, no technical changes.

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